



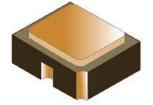
# **PNP Small Signal Silicon Transistor**

Qualified per MIL-PRF-19500/511

Qualified Levels: JAN, JANTX, JANTXV and JANS

### **DESCRIPTION**

This 2N4261UB small signal transistor features ceramic bodied construction with a metal lid for military grade products per MIL-PRF-19500/511. It is also available with a ceramic lid in the UBC package or in a hermetically sealed metal TO-72 package.







Important: For the latest information, visit our website <a href="http://www.microsemi.com">http://www.microsemi.com</a>.

### **FEATURES**

- Surface mount equivalent of popular JEDEC registered 2N4261 number
- JAN, JANTX, JANTXV and JANS qualification is available per MIL-PRF-19500/511 (See <u>part nomenclature</u> for all available options.)
- RoHS compliant

# **APPLICATIONS / BENEFITS**

- Low-profile ceramic bodied surface mount package (see package illustration)
- Lightweight
- · Military and other high-reliability applications

# Also available in:

UBC package

(Ceramic Lid surface mount)

2N4261UBC

TO-72 package

(leaded) 2N4261

# MAXIMUM RATINGS @ T<sub>A</sub> = 25 °C

Parameters/Test Conditions	Symbol	Value	Unit	
Junction and Storage Temperature	T <sub>J</sub> & T <sub>STG</sub>	-65 to +200	°C	
Thermal Resistance Junction-to-A	mal Resistance Junction-to-Ambient (1)			
Collector – Emitter Voltage		$V_{CEO}$	-15	V
Collector – Base Voltage		V <sub>CBO</sub>	-15	V
Emitter - Base Voltage		$V_{EBO}$	-4.5	V
Total Power Dissipation (1)	@ $T_A = +25  {}^{\circ}C^{(1)}$ @ $T_C = +25  {}^{\circ}C^{(2)}$	P <sub>T</sub>	0.2	W
Collector Current		Ic	-30	mA

NOTES: 1. Derate linearly 1.14 mW/°C above T<sub>A</sub> = +25°C

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# **MECHANICAL and PACKAGING**

- CASE: Ceramic
- TERMINALS: Gold plating over nickel under plate
- MARKING: Part number, date code, manufacturer's ID
- TAPE & REEL option: Standard per EIA-418D. Consult factory for quantities.
- WEIGHT: Less than 0.04 grams
- See <u>Package Dimensions</u> on last page.

# ANT 2N4261 UB Reliability Level JAN = JAN level JANTX = JANTX level JANTXV = JANTXV level JANS = JANS level Blank = Commercial grade JANTX = JANTXV = JANTXV | JANT

	SYMBOLS & DEFINITIONS							
Symbol	Definition							
I <sub>B</sub>	Base current: The value of the dc current into the base terminal.							
Ic	Collector current: The value of the dc current into the collector terminal.							
$V_{CB}$	Collector-base voltage: The dc voltage between the collector and the base.							
V <sub>CBO</sub>	Collector-base voltage, base open: The voltage between the collector and base terminals when the emitter terminal is open-circuited.							
V <sub>CE</sub>	Collector-emitter voltage: The dc voltage between the collector and the emitter.							
V <sub>CEO</sub>	Collector-emitter voltage, base open: The voltage between the collector and the emitter terminals when the base terminal is open-circuited.							
V <sub>CC</sub>	Collector-supply voltage: The supply voltage applied to a circuit connected to the collector.							
V <sub>EBO</sub>	Emitter-base voltage, collector open: The voltage between the emitter and base terminals with the collector terminal open-circuited.							
$V_{EB}$	Emitter-base voltage: The dc voltage between the emitter and the base							



# ELECTRICAL CHARACTERISTICS @ 25 °C unless otherwise noted

Parameters / Test Conditions	Symbol	Min	Max	Unit
OFF CHARACTERISTICS				
Collector-Emitter Breakdown Voltage I <sub>C</sub> = -10 mA	V <sub>(BR)CEO</sub>	-15		V
Collector-Base Cutoff Current V <sub>CB</sub> = -15 V	I <sub>CBO</sub>		-10	μΑ
Emitter-Base Cutoff Current V <sub>EB</sub> = -4.5 V	I <sub>EBO</sub>		-10	μΑ
Collector-Emitter Cutoff Current $V_{CE} = -10 \text{ V}, V_{BE} = -0.4 \text{ V}$ $V_{CE} = -10 \text{ V}, V_{BE} = -2.0 \text{ V}$	I <sub>CEX</sub>		-50 -5	nA nA
ON CHARACTERISTICS (1)				
Forward-Current Transfer Ratio $I_C = -1.0 \text{ mA}, V_{CE} = -1.0 \text{ V}$ $I_C = -10 \text{ mA}, V_{CE} = -1.0 \text{ V}$ $I_C = -30 \text{ mA}, V_{CE} = -1.0 \text{ V}$	h <sub>FE</sub>	25 30 20	150	
Collector-Emitter Saturation Voltage $I_C = -1.0 \text{ mA}, I_B = -0.1 \text{ mA}$ $I_C = -10 \text{ mA}, I_B = -1.0 \text{ mA}$	$V_{CE(sat)}$		-0.15 -0.35	V
Base-Emitter Saturation Voltage (Non-Saturated) $V_{CE}$ = -1.0 V, $I_{C}$ = -1.0 mA $V_{CE}$ = -1.0 V, $I_{C}$ = -10 mA	V <sub>BE</sub>		-0.8 -1.0	V

# **DYNAMIC CHARACTERISTICS**

Parameters / Test Conditions	Symbol	Min	Max	Unit
Magnitude of Small–Signal Forward Current Transfer				
Ratio	h <sub>fe</sub>			
$I_C = -5.0 \text{ mA}, V_{CE} = 4.0 \text{ V}, f = 100 \text{ MHz}$	IIfe	15		
$I_C = -10 \text{ mA}, V_{CE} = 10 \text{ V}, f = 100 \text{ MHz}$		20		
Output Capacitance	C		2.5	nΕ
$V_{CB} = -4 \text{ V}, I_{E} = 0, 100 \text{ kHz} \le f \le 1.0 \text{ MHz}$	$C_{obo}$		2.5	pF
Input Capacitance	C <sub>ibo</sub>		2.5	pF
$V_{EB} = -0.5V, I_C = 0, 100 \text{ kHz} \le f \le 1.0 \text{ MHz}$	Oibo		2.0	Рι

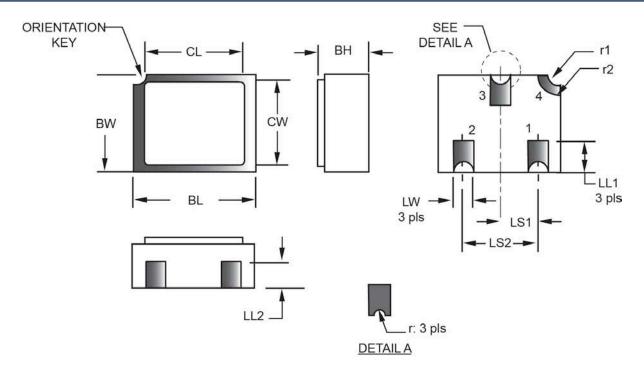
# **SWITCHING CHARACTERISTICS**

Parameters / Test Conditions	Symbol	Min	Max	Unit
Turn-On Time $V_{CC} = -17 \text{ V}; I_C = -10 \text{ mA}$	ton		2.5	ns
Turn-Off Time $V_{CC} = -17 \text{ V}; I_C = -10 \text{ mA}$	t <sub>off</sub>		3.5	ns

(1) Pulse Test: pulse width = 300  $\mu$ s, duty cycle  $\leq$  2.0%



# **PACKAGE DIMENSIONS**



Symbol	Dimensions					Dimensions					
	inch millir		limeters Note		Symbol	inch		millimeters		Note	
	Min	Max	Min	Max		N	Min	Max	Min	Max	1
ВН	0.046	.056	1.17	1.42		LS1	0.035	0.039	0.89	0.99	
BL	0.115	0.128	2.92	3.25		LS2	0.071	0.079	1.80	2.01	
BW	0.085	0.108	2.16	2.74		LW	0.016	0.024	0.41	0.61	
CL	-	0.128	-	3.25		r	-	0.008	-	0.20	
CW	-	0.108	-	2.74		r1	-	0.012	-	0.31	
LL1	0.022	0.038	0.56	0.97		r2	-	0.022	-	.056	
LL2	0.017	0.035	0.43	0.89							

# NOTES:

- 1. Dimensions are in inches. Millimeters are given for information only.
- Ceramic package only.
   Hatched areas on package denote metallized areas.
- 4. Pad 1 = Base, Pad 2 = Emitter, Pad 3 = Collector, Pad 4 = Shielding connected to the lid.
- 5. In accordance with ASME Y14.5M, diameters are equivalent to Φx symbology.